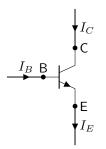
## Transistor Cheat Sheet

### Rafael Marinho

# **Bipolar transistor (NPN)**

## **General Node Equations**



$$V_{CE} = V_{CB} + V_{BE}$$

$$I_E = I_C + I_B$$

$$I_C = \beta I_B$$

$$\beta = \frac{\alpha + 1}{\alpha}$$

$$\alpha = \frac{\beta}{\beta + 1}$$

$$\beta = \beta_F \left( 1 + \frac{V_{CB}}{V_T} \right)$$

$$I_{C}$$

$$I_{C}$$

$$I_{E} = I_{C} + I_{B}$$

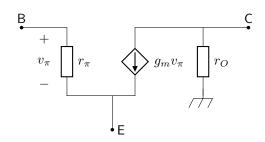
$$I_{C} = \beta I_{B}$$

$$\beta = \frac{\alpha + 1}{\alpha}$$

$$\alpha = \frac{\beta}{\beta + 1}$$

$$I_{C} = I_{S} \exp\left(\frac{V_{BE}}{V_{T}}\right)$$

## Small-signal model



$$r_{\pi} = \frac{V_T}{I_{B0}} \qquad \qquad g_m = \frac{I_{C0}}{V_T} \qquad \qquad r_O = \frac{V_A}{I_{C0}}$$

$$g_m = \frac{I_{C0}}{V_T}$$

$$r_O = \frac{V_A}{I_{C0}}$$

## **Amplifiers**

#### Common-Emitter (CE)

without degeneration

with degeneration

$$\begin{aligned} A_V &= -g_m R_C \\ R_{in} &= (R_B \| r_\pi) \\ R_{out} &= R_C \end{aligned} \qquad \begin{aligned} A_V &= \frac{-g_m R_C}{1 + \left(\frac{1}{r_\pi} + g_m\right) R_E} \\ R_{in} &= \left(R_E \| R_{in,B}\right) \\ R_{in,B} &= r_\pi \left[1 + \left(\frac{1}{r_\pi} + g_m\right) R_E\right] \\ R_{out} &= R_C \end{aligned}$$

#### Common-Base (CB)

for 
$$V_A = \infty$$

$$A_V = g_m R_C$$
 
$$R_{in} = (r_\pi || R_C || \frac{1}{g_m})$$
 
$$R_{in} \approx \frac{1}{g_m}, \text{ for } I_C >> I_B$$
 
$$R_{out} = R_C$$

#### Common-Collector (CC)

$$\text{ for } V_A = \infty$$

$$A_{V} = \frac{-g_{m}R_{C}}{1 + \frac{1}{R_{E}\left(\frac{1}{r_{\pi}} + g_{m}\right)}}$$

$$R_{in} = r_{\pi} + (1 + \beta)R_{E}$$

$$R_{out} = (R_{E}||R_{in,B}||\frac{1}{g_{m}})$$